

## SANYO Semiconductors DATA SHEET

# **CPH3331**-

P-Channel Silicon MOSFET

## General-Purpose Switching Device **Applications**

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-200	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ΙD		-0.4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-1.6	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-200			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-200V, V <sub>GS</sub> =0			-10	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =-10V, I <sub>D</sub> =-200mA	0.54	0.9		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	ID=-200mA, VGS=-10V		3.8	5.0	Ω
	RDS(on)2	ID=-200mA, VGS=-4V		4	5.6	Ω
Input Capacitance	Ciss	V <sub>DS</sub> =-20V, f=1MHz		350		pF
Output Capacitance	Coss	V <sub>DS</sub> =-20V, f=1MHz		17		pF
Reverse Transfer Capacitance	Crss	VDS=-20V, f=1MHz		11		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		10		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		4		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		43		ns
Fall Time	tf	See specified Test Circuit.		42		ns

Marking: YG Continued on next page.

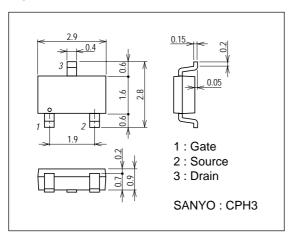
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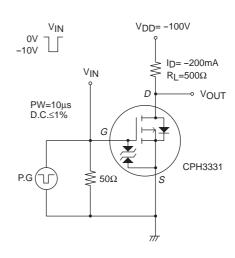
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Total Gate Charge	Qg	V <sub>D</sub> S=-100V, V <sub>G</sub> S=-10V, I <sub>D</sub> =-400mA		7.0		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =-100V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-400mA		1.0		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>D</sub> S=-100V, V <sub>G</sub> S=-10V, I <sub>D</sub> =-400mA		0.8		nC
Diode Forward Voltage	VSD	IS=-400mA, VGS=0		-0.79	-1.2	V

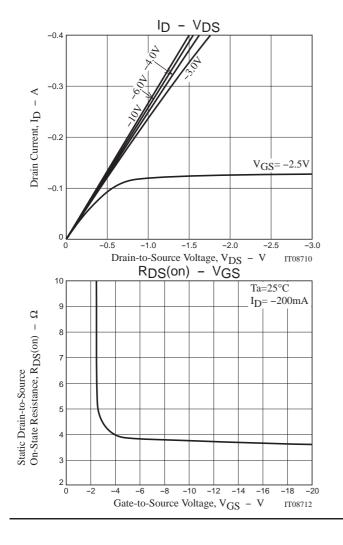
### **Package Dimensions**

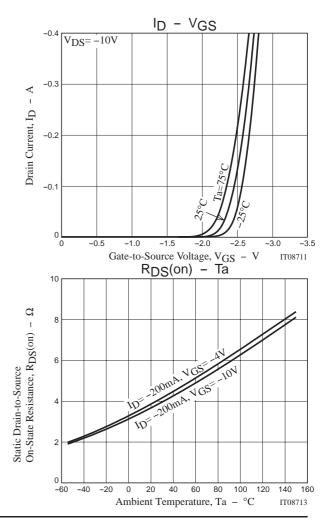
unit : mm 2152A

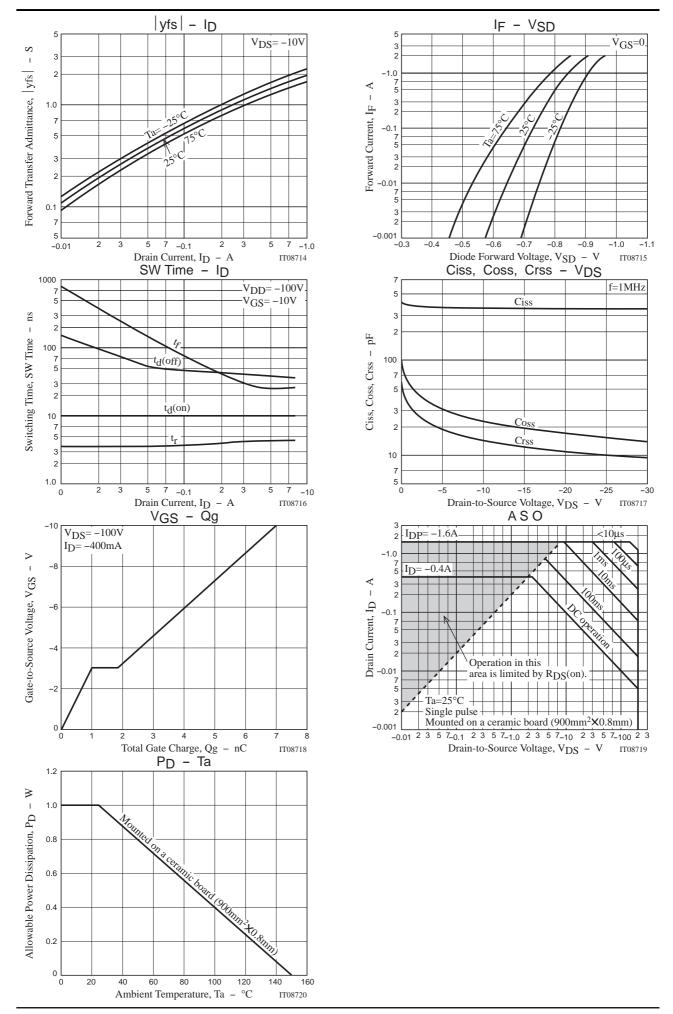


## **Switching Time Test Circuit**









Note on usage: Since the CPH3331 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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